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Structural properties of carbon composites doped with boron

The article considers morphology, chemical and phase composition of composite boro-carbon coatings, received by ion-plasma synthesis, depending on the boron content. Specimens of carbon coating doped with boron were obtained in vacuum unit by combined method coupled with co-deposition of carbon layer from pulse carbon plasma and its doping with boron atom flow. The obtained specimens of composite CC had embedded boron atoms with various concentration (N_B), namely, 2.3 at.% were contained in $\alpha\text{-C}_{91.2}\text{B}_{2.3}$, in $\alpha\text{-C}_{79.3}\text{B}_{17.4}$ — 17.4 at.%, in $\alpha\text{-C}_{53.3}\text{B}_{43.2}$ — 43.2 at.%. Carbon structures and carbon clusters graphitization were examined by X-ray photoelectron spectroscopy and Raman spectroscopy. Aiming at chemical interaction between carbon and boron in CC establishment we conducted mathematical processing of XPS for energy states C1s, B1s, O1s of carbon, boron and oxygen atoms. XPS C1s was presented as peaks superposition with centers located at 284.5; 285.5; 283.5 and 288 eV and consequently responsible for Csp^2 , Csp^3 , C–B and C–O carbon atom interaction. With the growth of N_B in boron-doped carbon coating a grain structure is formed, its size and grain orientation regarding the surface of the substrate increase, resulting in a decrease in the coating layer surface roughness.

Keywords: composite carbon coatings, boron doping, atomic force microscopy, X-ray photoelectron spectroscopy, Raman spectroscopy, clusters, boron carbide.

Introduction

Boron doping is considered to be an effective technological method of improving operational metal resources and their alloys [1]. Boron being the second solid element and having metal matrix in the volume as a separate phase, solid solution or chemical compound, deforms crystalline lattice and causes solid phase formation in materials that significantly increase their mechanical properties, thermal and wear resistance [2]. Boron on contact with carbon can form chemically stable boron carbide B_4C , which is resistant at temperature up to 2450 °C. These characteristics of boron determine high prospectivity of its use as a doping element in forming compositional carbon-contained coatings [3]. On [4] it is indicated, that phase and structural characteristics of such coatings are significantly defined by conditions and regimes of their formation by means of ion-plasma synthesis. In implementing of carbon layers' deposition methods from pulse cathode plasma, intensive thermal excitation processes are carried out, ionized particles streams having sufficiently high reaction activity are formed. At the same time carbon layers are condensed in the form of heterophase coatings containing carbon atoms in the state of sp^3 , sp^2 and even sp^1 -hybridized bonds. Such features of carbon coating (CC) deposition suggest that when they are doped with boron in the process of ion plasma synthesis it is possible to form a wide range of different phases in the layer structure, including based on chemical compounds. Composite materials with clusters from compounds on the basis of doping substance can have the same structure as nanocomposites based on polymer matrix [5].

The article considers structural properties of composite boron-carbon coatings obtained by ion-plasma synthesis based on their boron content.

Samples and research methods

Specimens of CC doped with boron were obtained in vacuum unit by combined method coupled with co-deposition of carbon layer from pulse carbon plasma and its doping with boron atom flow. Target evaporation from boron was conducted by pulsed radiation from solid-state YAG:Nd^{3+} laser at wavelength 1,064 nm in the frequency range of (f_L) 5 to 50 Hz. Boron atoms flow with pulse length 150 μs and frequency $f_L = 5, 30$ and 50 Hz was deposited on CC surface together with carbon plasma flow from vacuum-arc evaporator with pulse length 150 μs and frequency $f_C = 10$ Hz.

The elemental composition of the obtained α -C:B CC was regulated through changing of laser radiation pulse frequency f_L and was determined by X-ray photoelectron spectroscopy (XPS). X-ray photoelectron spectra of obtained carbon coatings were shot using PHI Quanta type, Japan.

The obtained specimens of composite CC had embedded boron atoms with various concentration (N_B), namely, 2.3 at.% were contained in α -C_{91.2}:B_{2.3}, in α -C_{79.3}:B_{17.4} — 17.4 at.%, in α -C_{53.3}:B_{43.2} — 43.2 at.%.

Carbon coating thickness was defined by means of transversal specimen chip with the help of scanning electron microscope (SEM) of Hitachi S-4800 type. A comparative analysis was carried out on CC specimens with the same effective thickness 363 ± 16 nm. Surface morphology of composite carbon coatings α -C:B was investigated with the help of atomic-force microscope (AFM) of Solver Pro and NT-MDT (Russia) types in topography and phase contrast measuring mode. The scanning field was $10 \times 10 \mu\text{m}^2$ at probe speed of 1.0 $\mu\text{m/s}$. High heterogeneous projections on the surface were monitored using the methods [6].

The microstructure of composite CC was studied by Raman spectroscopy at radiation excitation at wavelength 532 nm with power flow 20 mW using Senterra, Bruker.

The chemical composition and types of molecular bonds between carbon and boron atoms in the composite CC were determined by X-ray photoelectron spectroscopy using a PHI quanta 2 XPS device. XPS spectra were excited by Al (K α) cathode emission with the energy of 1486.6 eV at a voltage of 15 kW. The capacity of exciting radiation power was 25 W. The spectrum was collected in the area of interaction of the probing radiation with the surface of a spot CC specimen with a diameter of 100 μm . Bonds energy in XPS spectra was calibrated through C1s (284.6 eV). It should be noted that since the atomic sensitivity coefficient for boron (0.088) is significantly lower than for carbon C (0.205), the intensity of the B1s peak in XPS spectrum is significantly lower than that of the C1s peak.

Experimental results and their discussion

On Figure 1 SEM-images of CC specimen chip doped with boron are represented. It is seen that the structure of CC doped with boron differs from the structure of one-component α -C coating (Fig. 1, *a*). In the volume α -C:B of CC the formation of grain structure occurs, what is more, grain size depends on boron concentration N_B and increases with its growth: at a concentration ~ 2.3 at. % the structure becomes fine-grained, with its further growth N_B achieves ~ 43.2 at. % with grain formation in 3–3.5 times larger with marked orientation towards substrate surface [7]. There are no defects like pores or cracks on the surface and in the volume of deposited composite CC, as well as there are no substrate layers. The latter shows high adhesion of CC to silicon substrate.

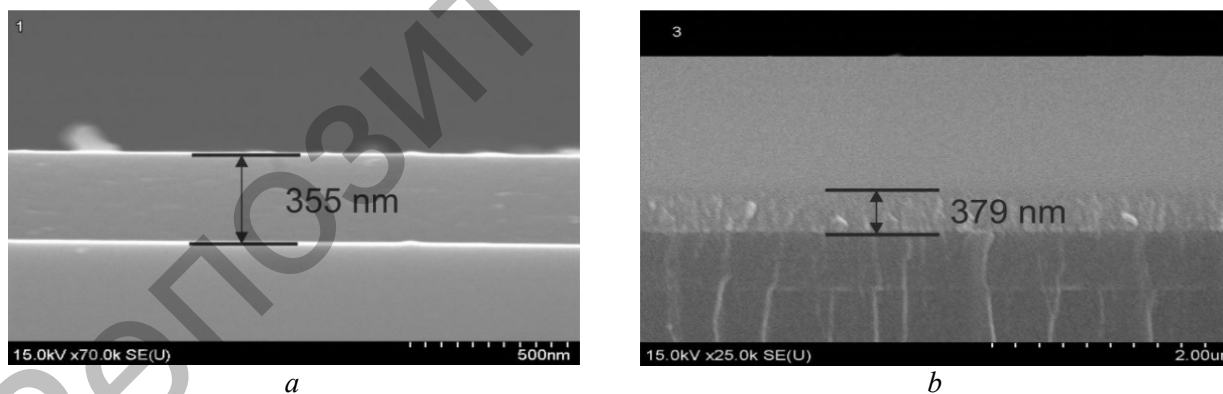


Figure 1. SEM-images of chip α -C (*a*) and α -C_{53.3}:B_{43.2} (*b*) of CC

On Figure 2 dependency diagram of N_C content of carbon component (curve 1) and average size of grain (R_g) in CC doped with boron is shown. The composition of elements of CC specimens, deposited together from pulse carbon plasma and boron atom flow doped with boron concentration 2.3 at.%, 17.4 at.% and 43.2 at.% with dopant boron atom flow frequency f_L increase changes essentially. Oxygen in CC structure is within the limits 2.4...6.5 at. % and in bound state with carbon mainly.

It can be seen that N_B increase in the coating leads to higher defectiveness of the composite CC and the formation of larger surface heterogeneities. Grain structure increase of boron-doped CC is caused by high activity of agglomeration processes with formation of boron in initial one-component carbon material. Grain

size increase R_g in boron-carbon coating with higher boron content N_B is consistent with diamond-like films morphology data [8].

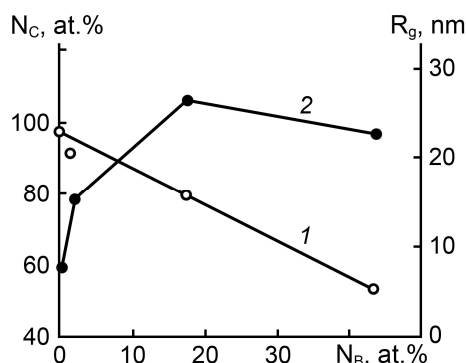


Figure 2. Dependency diagram of carbon component N_C content (1) and grain R_g average size (2) in CC structure on N_B concentration of dopant boron atoms.

It should be noted that geometric parameters of CC structural state, surface roughness (R_{ms}) and grain R_g average size of the layer structure depend on conditions and modes of the coating process. Thus, one-component α -C of CC, deposited from pulse flows, are characterized by low values R_{ms} , that can be explained by small sizes and clusters close packing Csp^3 [9].

On Figure 3 typical Raman spectra α -C (a) and α -C_{53.3}:B₄₃ (b) of CC are presented. Raman spectra (RS) envelope shape of all CC is peculiar to amorphous CC, containing carbon atoms both in sp^2 and sp^3 bond hybridization state.

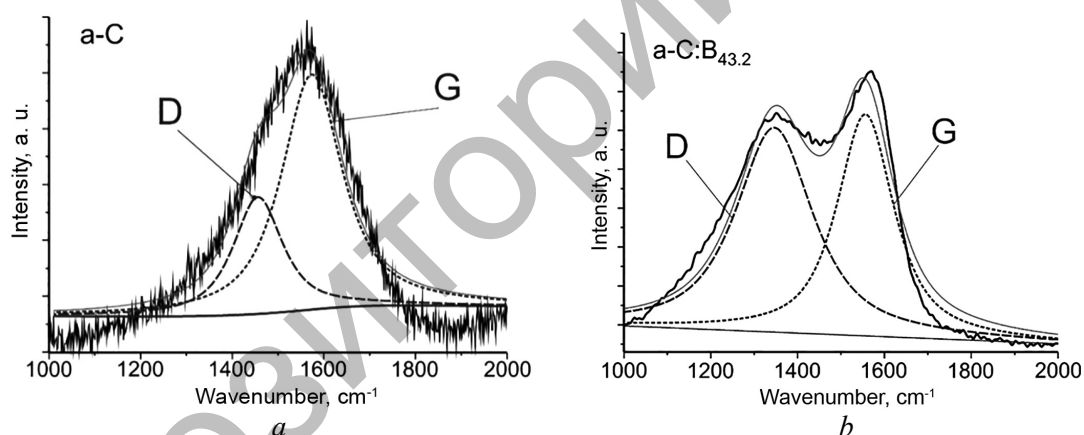


Figure 3. Raman-spectra α -C (a) and α -C_{53.3}:B₄₃ (b) of CC

Figure 3 shows that RS of boron-carbon CC have broad asymmetric peak in the range 1000 to 2000 cm^{-1} , that according to [10] contains information about sp^2 hybridized carbon bonds, order degree and relative size of carbon clusters Csp^2 and Csp^3 . Raman spectrum can be represented in superposition of peaks (G-peak and D-peak) by Gaussian function. Herewith theoretical curve, being the result of spectrum simulation, is well consistent to basic experimental data that testifies the certainty of RS mathematical processing.

With N_B growth in CC changes of RS relative to intensity ratio of D- and G-peaks occur (Fig. 3, Table 1), that are determined not only by changes of Csp^2 and Csp^3 clusters quantity and size in accordance with [11], but also by metal content in the layer, its chemical activity. There is molecular bonds process between carbon and boron that leads to changes of carbon clusters degree of order.

It was found that at $N_B = 2.3$ at. % in carbon coating D- and G-peaks intensity ratio insignificantly changes in comparison with RS parameters of one-component carbon coating. It indicates little impact of small N_B on the ordering degree and relative distribution of Csp^2/Csp^3 carbon phases in the coating.

With N_B growth in CC D-peak intensity increase occurs, as well as G-peak centreshift towards lower values of wave numbers. Essential changes of RS shape and I_D/I_G ratio increase (Table 1) for carbon coatings α -C highly doped with boron (Fig. 3, b) ($N_B = 43.2$ at. %) happen.

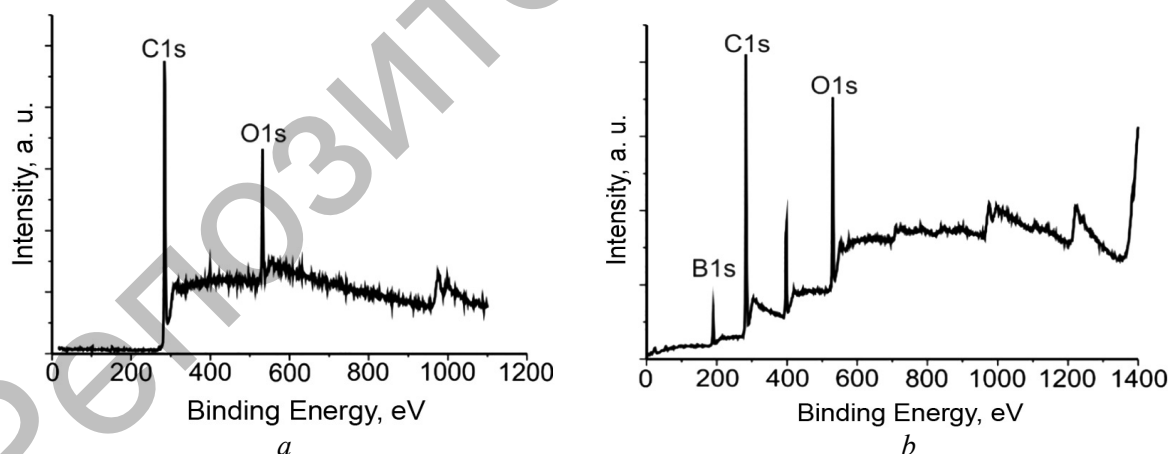
Parameters of the Raman spectra of carbon coatings doped with boron

Type of CC	f_L , Hz	N_C , at. %	N_B , at. %	N_O , at. %	I_D/I_G	Position of G-peak, cm^{-1}	Width of G-peak, cm^{-1}
α -C	–	97.6	–	2.4	0.58	1573.5	157.2
α -C _{91.2} :B _{2.3}	5	91.2	2.3	6.5	0.62	1571.3	168.7
α -C _{79.3} :B _{17.4}	33	79.3	17.4	3.3	0.73	1552.3	189.9
α -C _{53.3} :B _{43.2}	50	53.3	43.2	3.5	1.25	1556.2	155.7

In accordance with [12] CC received from pulse flows of carbon plasma are characterized by high mechanical properties under the condition ($I_D/I_G \leq 1$) and for CC α -C carbon atom concentration with sp^3 hybridized bonds increases with I_D/I_G ratio reduction. According to Table 1 with N_B growth up to 17.4 at. % some I_D/I_G ratio increase is observed in the coating, that indicates the reduction of carbon atom concentration with sp^3 hybridized bonds.

Together with the increase of I_D/I_G ratio G-peak shifting toward lower wave numbers in comparison with peak's position for CC α -C takes place. According to [13] such change corresponds to the decrease of carbon matrix ordering degree and is defined by carbon atom concentration degree with sp^3 hybridized bonds. Based on data from Table 1 we can conclude that the shifting of G-peak position and insignificant value increase of I_D/I_G ratio, typical of CC α -C with $N_B = 2.3$ at. % and 17.4 at. %, are caused by the concentration growth of CC Csp^3 . In [12] it is shown that the increase in carbon atoms number in sp^3 hybridized bonds is probably connected with C–B bonds formation in CC, while boron interacts mainly with carbon atoms with sp^3 hybridization. It leads to the growth of structural heterogeneity that causes the ordering degree decrease of carbon clusters Csp^2 and shows in RS of CC as G-peak broadening. At high N_B value the density reduction of sp^3 bonds occurs in CC.

X-ray photoelectron spectroscopy (XPS) analysis for CC α -C and α -C:B presented on Figure 4 shows that except boron there is also oxygen in the surface layer in the bond state with carbon (C–O) and boron (B–O). These bonds are formed at the stage of CC deposition as a result of interaction of carbon and boron components with oxygen in the operating environment of the vacuum chamber, as well as at its depressurization. Since the contribution of oxygen C–O and B–O — bonds to the integrated intensity was insignificant in relation to the total basic peaks area, their impact on CC structure and properties was not studied.

Figure 4. XPS α -C (a) and α -C:B_{43.2} (b) CC

Aiming at chemical interaction between carbon and boron in CC establishment we conducted mathematical processing of XPS for energy states C1s, B1s, O1s of carbon, boron and oxygen atoms. XPS C1s was presented as peaks superposition with centers located at 284.5; 285.5; 283.5 and 288 eV and consequently responsible for Csp^2 , Csp^3 , C–B and C–O carbon atom interaction [14].

X-ray photoelectronic spectrum B1s can be considered as the peaks superposition characteristic of B–O, B–C and B–B interactions and located at energies 190.7, 189.4 and 190 eV correspondently.

There are peaks typical of O–C, O–O and O–B bonds in X-ray photoelectronic spectrum of oxygen O1s. As a result of statistical data processing of C1s XPE-spectrum it was found that integrated area share for C–O bonds does not exceed 5 %.

XPS for boron doped CC ambiguously depend on N_B value in CC. At low boron N_B (2.3 at. %) B–C carbene bonds are mainly formed. With further N_B growth B–B bonds increase in the structure of composite CC occurs. However, at high N_B value (43.2 at. %) we observe carbon matrix restructuring with dominant Csp^2 and carbide phases content in CC volume. There is some C- sp^3 -peak shiftcenter (up to ~ 0.3 eV) towards higher energies as well as the reduction of this peak half-width at N_B increase in CC. It can be connected with the presence of more than one heterophase forming the structure in CC [15], as well as the development of competing forming processes in the coating layer of carbide compounds and boron oxide.

With N_B growth we observe the reduction of Csp^3 carbon atom bonds and considerable increase of B–C-bonds, characteristic of boron carbide in the coating. It can be assumed that Csp^3 reduction of carbon clusters is caused by their replacement for boron carbide. It corresponds to the results of CC RS analysis where graphitization of carbon structure and orientation increase of carbon Csp^2 -clusters due to boron bonds with carbon atoms in sp^3 hybridization state are observed. Such phase changes in CC with different N_B values allow for their high mechanical properties preservation.

Conclusion

The structural properties of composite boron-carbon coatings obtained by ion-plasma synthesis are largely determined by the boron content in them. At a low concentration of NB (2.3 at.%) Boron, bonds with carbon of the B–C type are predominantly formed. With the growth of N_B in boron-doped carbon coating a grain structure is formed, its size and grain orientation regarding the surface of the substrate increase, resulting in a decrease in the coating layer surface roughness. An increase in the grain size of the structure of boron-doped UPs is caused by the high activity of agglomeration processes with the formation of boron-containing microvolumes in the original one-component carbon material. With the subsequent growth of NB, there is an increase in the B–B bonds in the structure of the composite UP. Also, the increase of N_B in carbon coating structure leads to the reduction of carbon phase content with sp^3 hybridized bonds and is replaced by boron carbide clusters. It is confirmed by graphitization of carbon structure and increase of carbon Csp^2 clusters due to chemical boron and carbon atoms interaction in the state with sp^3 hybridized bonds. At a high NB value (43.2 at.%), The structure of the carbon matrix is restructured with a predominant content of Csp^2 and carbide phases in the volume.

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Бормен легирленген көміртекті композициялық материалдардың құрылымдық қасиеттері

Мақалада бордың құрамына байланысты ион-плазмалық синтез нәтижесінде алынған бор-көміртегі композицияларының морфологиясы, химиялық және фазалық құрамы қарастырылған. Бормен байланған көміртегі жабынының (КЖ) үлгілері вакуумдық қондырғыда импульсті көміртегі плазмасынан көміртегі қабатының түсуімен және бор атомдары ағымының тұтасуымен алынған. Алынған композициялық КЖ үлгілерінде әртүрлі концентрациясы бар бор атомдары, атап айтқанда 2,3 % болды, олар $\alpha\text{-C}_{91,2}\text{:B}_{2,3}$, $\alpha\text{-C}_{79,3}\text{:B}_{17,4}$ — 17,4 ат.%, $\alpha\text{-C}_{53,3}\text{:B}_{43,2}$ — 43,2 ат.%. Көміртекті құрылымдар және көміртегі кластерлерінің графитизациясы рентгендік фотоэлектронды спектроскопия (XPS) және раман спектроскопиясымен зерттелді. КЖ құру кезінде көміртегі пен бордың химиялық өзара әрекеттесуі мақсатында C1s, B1s, O1s атомдарының көміртегі, бор және оттегі энергетикалық күйлері үшін XPS математикалық өңдеу жүргізілді. XPS C1s 284,5-де орналасқан орталықтары бар шыңдардың суперпозициясы ретінде ұсынылды; 285,5; 283,5 және 288 эВ, демек, Csp^2 , Csp^3 , C–B және C–O көміртегі атомдарының өзара әрекеттесуіне жауап береді. N_B өсуімен бормен қапталған көміртегі жабындыда түйіршікті құрылым пайда болады, оның мөлшері мен астықтың субстрат беткейінің ұлғаюына қарай бағдарлануы қабатының беттік кедір-бұдырының төмендеуіне әкеледі.

Кілт сөздер: композициялық көміртегі жабыны, бор тамшысының пайда болуы, атомдық күш микроскопиясы, рентгендік фотоэлектронды спектроскопия, раман спектроскопиясы, кластерлер, бор карбиді.

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Структурные свойства углеродных композиционных материалов, легированных бором

В статье рассмотрены морфология, химический и фазовый состав композиционных боруглеродных покрытий, полученных ионно-плазменным синтезом, в зависимости от содержания бора. Образцы углеродного покрытия (УП), легированного бором, были получены в вакуумной установке комбиниро-

ванным способом в сочетании с осаждением углеродного слоя из импульсной углеродной плазмы и его легированием потоком атомов бора. Полученные образцы композиционных УП содержали внедренные атомы бора с различной концентрацией (N_B), а именно 2,3 ат.% содержались в $\alpha\text{-C}_{91,2}\text{:B}_{2,3}$, в $\alpha\text{-C}_{79,3}\text{:B}_{17,4}$ — 17,4 ат.%, в $\alpha\text{-C}_{53,3}\text{:B}_{43,2}$ — 43,2 ат.%. Структуры углерода и графитизация углеродных кластеров были исследованы методами рентгеновской фотоэлектронной спектроскопии (XPS) и рамановской спектроскопии. С целью химического взаимодействия между углеродом и бором при создании УП была проведена математическая обработка XPS для энергетических состояний C1s, B1s, O1s атомов углерода, бора и кислорода. XPS C1s была представлена как суперпозиция пиков с центрами, расположенными в 284,5; 285,5; 283,5 и 288 эВ, и, следовательно, они являлись ответственными за взаимодействие атомов углерода Csp^2 , Csp^3 , C–B и C–O. С ростом N_B в углеродном покрытии, легированном бором, образуется зернистая структура, увеличиваются ее размер и ориентация зерен относительно поверхности подложки, что приводит к уменьшению шероховатости поверхности слоя покрытия.

Ключевые слова: композитные углеродные покрытия, каплеобразование бора, атомно-силовая микроскопия, рентгеновская фотоэлектронная спектроскопия, комбинационная спектроскопия, кластеры, карбид бора.

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